

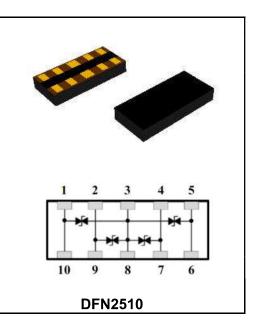
4 Channel Ultra-low Capacitance ESD Protection

Features

Ultra-Low capacitance:0.05pF(typ.)
Low leakage current(<100nA)
Fast response time(<1ns)
Bi-directional,single line protection
IEC 61000-4-2 (ESD Air): 15kV
IEC 61000-4-2 (ESD Contact): 8kV

Application

USB 3.0/3.1
HDMI 1.3/1.4/2.0
RF Antenna
SATA and eSATA Interface



Order Information

Part Number	Package	Size (mm)	Delivery Form	Delivery Quantity
PESD2510D05	DFN2510	2.50X1.00X0.50	7" T&R	3000PCS/Tape

Limiting Values(TA = 25 °C, unless otherwise specified)

Symbol	Parameter Conditions		Min	Мах	Unit
VESD		IEC 61000-4-2; Contact Discharge	-	8	kV
VESD	Electrostatic Discharge Voltage	IEC 61000-4-2; Air Discharge	-	15	kV
ТА	Operating Temperature Range	-	-40	90	°C
Tstg	Storage Temperature Range	-	-55	125	°C

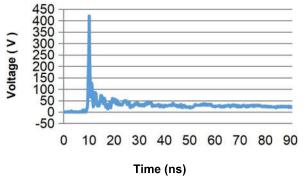
Electrical Characteristics(TA = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур.	Мах	Unit
VDC	Continuous Operating Voltage	-	-	-	5.0	V
VT	Trigger Voltage	IEC61000-4-2 8kV contactdischarge	-	450	-	V
VC	Clamping Voltage	IEC61000-4-2 8kV contactdischarge	-	40	-	V
IL	Leakage Current	DC 5V shall be appliedon mponent	-	-	100	nA
CJ	Capacitance	Measured at 10MHz	-	0.05	-	pF





R





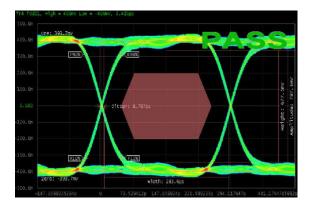
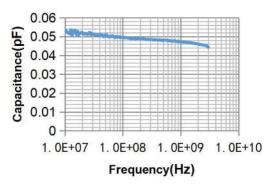


Fig.3 HDMI 1.4 Mask at 3.4 Gbps



Fig.5 HDMI 2.0 Mask at 6.0 Gbps





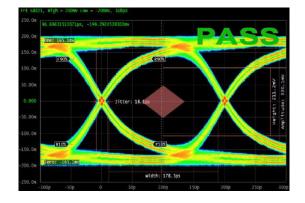


Fig.4 USB 3.0 Mask at 5.0 Gbps

PESD2510D05



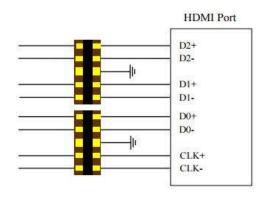


Fig.6 ESD Protection for HDMI

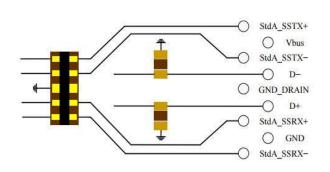


Fig.7 ESD Protection for USB 3.0 Type A

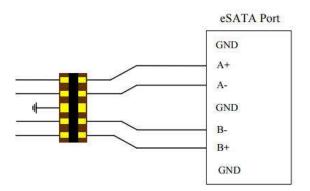
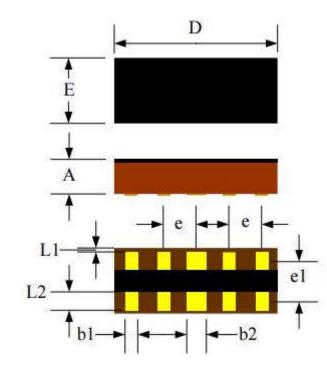
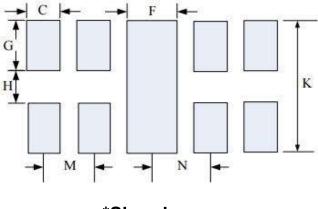


Fig.8 ESD Protection for eSATA





Recommended Solder Pad Footprint



*Sizes in mm

Notes:

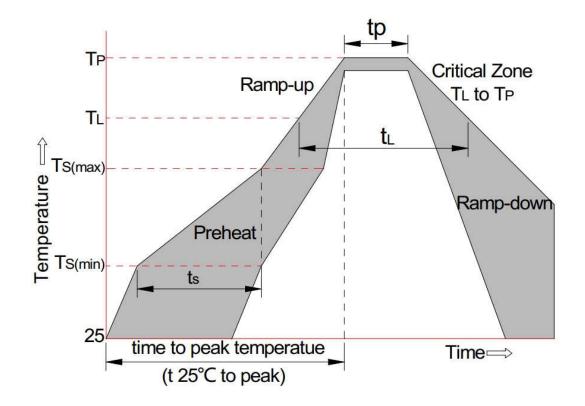
This solder pad layout is for reference purposes only.

Dimension	Unit: Millimeters		
	Min.	Max.	
А	0.40	0.60	
b1	0.10	0.30	
b2	0.20	0.40	
D	2.40	2.60	
E	0.90	1.10	
е	0.40	0.60	
e1	0.50	0.70	
L1	0.04	0.06	
L2	0.20	0.40	
	1		

Dimension	Unit: Millimeters		
	Min.	Max.	
С	0.20	0.30	
F	0.35	0.45	
G	0.55	0.65	
Н	0.25	0.35	
К	1.40	1.60	
М	0.45	0.55	
N	0.45	0.55	







Reflow Condition		Pb-Free Assembly		
	-Temperature Min (Ts(min))	+150°C		
Pre-heat	-Temperature Max(Ts(max))	+200°C		
	-Time (Min to Max) (ts)	60-180 secs.		
Average ran	np up rate (Liquid us Temp (TL) to peak)	3°C/sec. Max		
Ts(max) to TL - Ramp-up Rate		3°C/sec. Max		
Reflow	-Temperature(TL)(Liquid us)	+217°C		
	-Temperature(tL)	60-150 secs.		
Peak Temp (Tp)		+260(+0/-5)°C		
Time within 5°C of actual Peak Temp (tp)		30 secs. Max		
Ramp-down Rate		6°C/sec. Max		
xTime 25°C to Peak Temp (TP)		8 min. Max		
Do not exceed		+260°C		



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